

## Features

- 4545 UVC LED
- ROHS and REACH Compliant
- MSL 3 qualified according to J-STD 020

## Description

The IN-C45PPATNU1 is a high-power UVC LED. It is a SMD type LED which can be used in various applications.

## Applications

- Medical applications
- Industrial facility applications

## **Recommended Solder Pattern**

(Suggest Stencil t=0.12 mm)

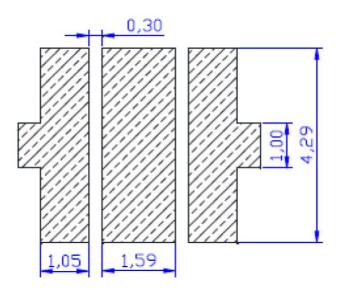


Figure 1. IN-C45PPATNU1 Recommended Solder Pattern

#### Note:

All dimensions are in millimeters. Tolerance is ±0.1mm unless other specified.



## **Package Dimensions**

(All dimensions are in mm, tolerance is  $\pm 0.1$ mm)

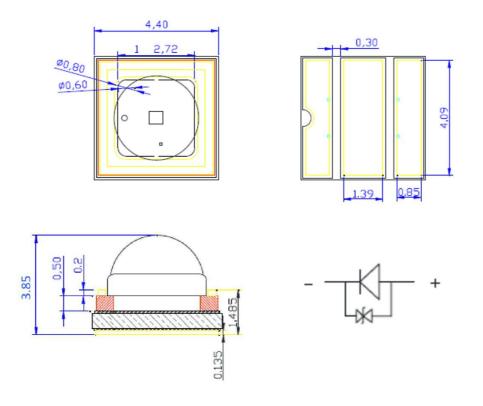


Figure 2. IN-C45PPATNU1 Package Dimension



### Absolute Maximum Rating at 25°C

Characteristics	Symbol	Min.	Typical	Max.	Unit
DC Forward Current	IF		700		mA
Power Dissipation	Pd		4.9		W
Junction Temperature	Tj			60	°C
Reverse Voltage	VR		5.0		V
Storage Temperature Range	Tstg	-40	-	100	°C
Operating Temperature	Topr	-10	-	60	°C
Soldering Temperature	Tsol		260		°C

#### Notes:

- 1. Operating the LED beyond the listed maximum ratings may affect device reliability and cause permanent damage.
- 2. The LEDs are not designed to be driven in reverse bias.

### Electronic-Optical Characteristics (Ambient Temp: 25°C)

Characteristics	Symbol	Min.	Typical	Max.	Unit
DC Forward Current	IF		500		mA
Forward Voltage	VF	5.0	6.0	7.0	V
Radiant Flux	Фе	70	90		mW
Peak Wavelength	λρ	270	275	280	nm
Thermal Resistance	RTHJ-S		12.5		°C <b>/</b> W
Spectrum Half Width	Δλ		11		nm
Viewing Angle	201/2		30		Deg
Reverse Current	lr			10	μA

#### Note:

- 1. Forward Voltage(Vf) : ±0.1V
- 2. Peak Wavelength(λp) : ±5.0nm
- 3. Radiant Flux(Φe) : ±10%
- 4. Viewing angle $(2\theta 1/2) \pm 10^{\circ}$

### **ESD** Precaution

ATTENTION: Electrostatic Discharge (ESD) protection

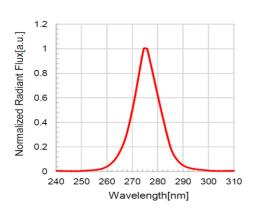


The symbol above denotes that ESD precaution is needed. ESD protection for GaP and AlGaAs based chips is necessary even though they are relatively safe in the presence of low static-electric discharge. Parts built with AlInGaP, GaN, or/and InGaN based chips are STATIC SENSITIVE devices. ESD precaution must be taken during design and assembly. If manual work or processing is needed, please ensure the device is adequately protected from ESD during the process.

Please be advised that normal static precautions should be taken in the handling and assembly of this device to prevent damage or degradation which may be induced by electrostatic discharge (ESD).

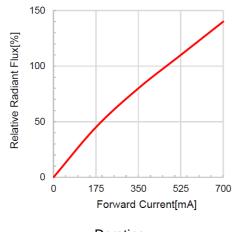


### **Typical Characteristics Curves**



**Relative Spectral Power Distribution** 

Relative Radiant Flux vs. Forward Current (Ta=25°C)



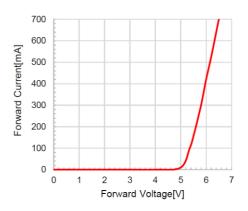




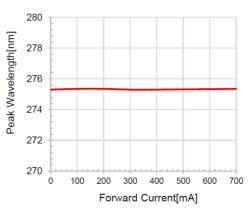


Viewing angle  $(2\theta 1/2) \pm 10^{\circ}$ 

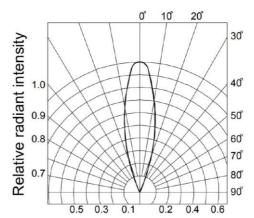
### Forward Current vs. Forward Voltage (Ta=25°C)



### Peak wavelength vs. Forward Current (Ta=25°C)



#### **Radiation Characteristics**





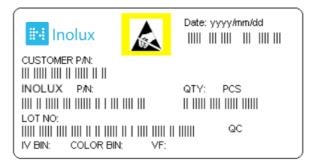
## **Ordering Information**

Peak Wavelength Range	Beam Angle Forward Voltage(V)		Forward Voltage(V)		
		Min	Max		
U1: 270~280nm	30°	5.0	7.0	IN-C45PPATNU1	

#### Notes:

1. Forward voltage (VF)  $\pm 0.5$ V, Radiometric Power (Po)  $\pm 15$ %.

## **Label Specifications**



## Inolux P/N:

Ι	Ν	-	С	4	5	РРА	Т	N	U1	-	Х	Х	Х	х
			Material	Pac	kage	Variation	Orientation	Current	Color			ustoi Stam		
Ino S№	lux 1D		C = Ceramic Type	45PPA = 4.5 x 4.5, 30 Deg.		T = Top Mount	N=500mA	U1 = 270- 280nm						

### Lot No.:

Z	2	0	1	7	01	24	001
Intern Track	Year (2017, 2018,)				Month	Date	Serial



# Forward Voltage Binning

	Voltage	unit: V@500mA	
Peak Wavelength	Bin Code	Min	Max
U1	А	5.0	6.0
270nm-280nm	В	6.0	7.0

Notes:

1. Binning current is 500 mA

# Radiant flux (Power) binning

Bin Code	Min. Po	Typ. Po
(500mA)	(mW)	(mW)
P1	70	90

Notes:

1. Binning current is 500mA

# Peak wavelength binning reference table

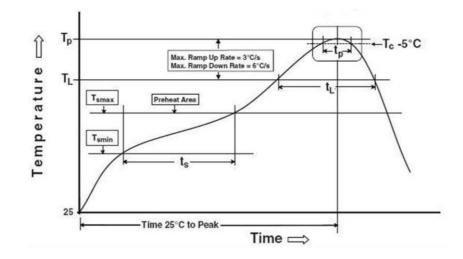
Bin code (500mA)	Min. Wp (nm)	Max. Wp (nm)
W280	270.0	280.0

#### Notes:

- 1. Peak-wavelength (Wp) tolerance:  $\pm$  2.0nm
- 2. Testing Current 500mA

# **Reflow Soldering**





Profile Feature	Lead Free Assembly
Average Ramp-Up Rate ( $T_L$ to $T_P$ )	3℃ / second max
Preheat Temperature Min (Tsmin)	150℃
Preheat Temperature Max (T <sub>Smax</sub> )	200°C
Preheat Time (ts)	60 – 120 seconds
Time Maintained Above Temperature (TL)	217°C
Time Maintained Above Time (t <sub>L</sub> )	60 – 150 seconds
Peak / Classification Temperature (T <sub>P</sub> )	260°C *
Time Within 5°C of Actual Peak Temperature (t $_{\text{P}})$	10~30 seconds
Ramp – Down Rate (T <sub>P</sub> to T <sub>L</sub> )	6℃ / second max
Time 25℃ to Peak Temperature	8 minutes max

The recommended peak temperature is 245 °C. The maximum soldering temperature should be controlled under 260 °C

## **Soldering Iron**

Basic Spec is  $\leq 4$  sec. when 260°C (+10°C  $\rightarrow$  -1 second). Power dissipation of Iron should be less than 15W. Surface temperature should be under 230°C

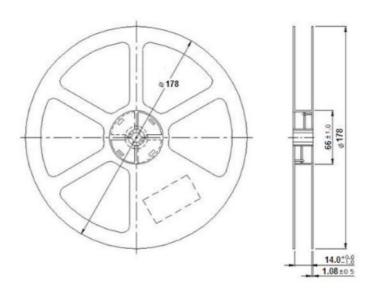
## Rework

Rework should be completed within 4 second under 245°C

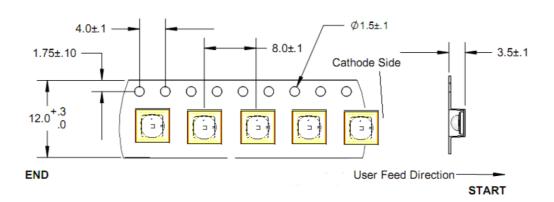


# Packing

## Reel



## Таре



### Notes:

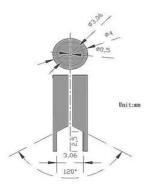
- 1. Each Reel (minimum number of pieces is 100 and maximum is 500 (30D) is packed in a moisture-proof bag along with 2 packs of desiccant and a humidity indicator card.
- **2.** Part No., Lot No., quantity should be indicated on the label of the moisture-proof bag and the cardboard box.



## Precautions

- 1. Recommendation for using LEDs
  - 1.1 The lens of LEDs should not be exposed to dust or debris. Excessive dust and debris may cause a drastic decrease in the luminosity.
  - 1.2 Avoid mechanical stress on LED lens.
  - 1.3 Do not touch the LED lens surface. It would affect the optical performance of the LED due to the LED lens' damage.
  - 1.4 Pick & place tools are recommended for the remove of LEDs from the factory tape & reel packaging
- 2. Pick & place nozzle

The pickup tool was recommended and shown as below



### 3. Lens handling

Please follow the guideline to pick LEDs

- 3.1 Use tweezers to pick LEDs
- 3.2 Do not touch the lens by using tweezers
- 3.3 Do not touch lens with fingers
- 3.4 Do not apply more than 4N of lens (400g) directly onto the lens

### 4. Lens cleaning

In the case which a small amount of dirt and dust particles remain on the lens surface, a suitable cleaning solution can be applied.

- 4.1 Try a gentle wiping with dust-free cloth
- 4.2 If needed, use dust-free cloth and isopropyl alcohol to gently clean the dirt from the lens surface.
- 4.3 Do not use other solvents as they may directly react with the LED assembly
- 4.4 Do not use ultrasonic cleaning which will damage the LEDs



### **Revision History**

Changes since last revision	Page	Version No.	<b>Revision Date</b>
Initial Release		1.0	03-19-2021

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